# HS-2620RH, HS-2622RH



### Data Sheet

## August 1999 File Number 4014.1

## Radiation Hardened, Very Wideband, High Input Impedance Uncompensated Operational Amplifiers

HS-2620RH and HS-2622RH are radiation hardened bipolar operational amplifiers that feature very high input impedance coupled with wideband AC performance. The high resistance of the input stage is complemented by low offset voltage (4mV Max at 25°C for HS-2620RH) and low bias and offset current (15nA Max at 25°C for HS-2620RH) to facilitate accurate signal processing. Offset voltage can be reduced further by means of an external nulling potentiometer. Closed loop gains greater than 5, the 25V/µs minimum slew rate at 25°C and the 100kV/V minimum open loop gain at 25°C, enables the HS-2620RH to perform high gain amplification of very fast, wideband signals. These dynamic characteristics, coupled with fast settling times, make these amplifiers ideally suited to pulse amplification designs as well as high frequency or video applications. The frequency response of the amplifier can be tailored to exact design requirements by means of an external bandwidth control capacitor. Other high performance designs such as high gain, low distortion audio amplifiers, high-Q and wideband active filters and high speed comparators are excellent uses of this part.

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed here must be used when ordering.

Detailed Electrical Specifications for these devices are contained in SMD 5962-95688. A "hot-link" is provided on our homepage for downloading.

www.intersil.com/spacedefense/space.asp

## Features

- Electrically Screened to SMD # 5962-95688
- QML Qualified per MIL-PRF-38535 Requirements
- Low Input Bias Current (HS-2620RH) ..... 15nA (Max) 5nA (Typ)
- Low Input Offset Voltage (HS-2620RH) . . . . . . 4mV (Max)
- Wide Gain Bandwidth Product (AV  $\geq$  5) . . . . . 100MHz (Typ)
- Output Short Circuit Protection

## Applications

- · Video and RF Amplifiers
- Pulse Amplifiers
- · Audio Amplifiers and Filters
- High-Q Active Filters
- High Speed Comparators

## **Ordering Information**

ORDERING NUMBER	INTERNAL MKT. NUMBER	TEMP. RANGE ( <sup>O</sup> C)
5962D9568801VGA	HS2-2620RH-Q	-55 to 125
5962D9568801VPA	HS7-2620RH-Q	-55 to 125
5962D9568801VPC	HS7B-2620RH-Q	-55 to 125
5962D9568802VGA	HS2-2622RH-Q	-55 to 125
5962D9568802VPA	HS7-2622RH-Q	-55 to 125
5962D9568802VPC	HS7B-2622RH-Q	-55 to 125

### Pinouts





HS2-2620RH, HS2-2622RH (CAN) MACY1-X8 TOP VIEW



## **Test Circuit**



NOTE: Includes stray capacitances.

FIGURE 1. TEST LOOP FOR THE HS-2620RH AND THE HS-2622RH

## Test Circuits and Waveforms



FIGURE 2. SIMPLIFIED TEST CIRCUIT



NOTE: Measured on both positive and negative transitions. Capacitance at Compensation pin should be minimized. FIGURE 4. OVERSHOOT, RISE AND FALL TIME WAVEFORMS

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## **Burn-In Circuits**

HS7-2620RH CERDIP HS7-2622RH CERDIP



HS2-2620RH (TO-99) METAL CAN HS2-2622RH (TO-99) METAL CAN



#### NOTES:

- 1. R1 = 1MΩ, ±5%, 1/4W (Min)
- 2.  $C1 = C2 = 0.01 \mu F/Socket$  (Min) of  $0.1 \mu F/Row$  (Min)
- 3. C3 = 0.01µF/Socket (10%)
- 4. D1 = D2 = IN4002 or Equivalent/Board
- 5.  $I(V+) (V -)I = 31V \pm 1V$

## Irradiation Circuit



NOTES:

- 6. V1 = +15V  $\pm 10\%$
- 7. V2 = -15V ±10%
- 8. R =  $1M\Omega \pm 5\%$
- 9. C =  $0.1 \mu F \pm 10\%$

## Schematic Diagram



## **Die Characteristics**

### DIE DIMENSIONS:

69 mils x 66 mils x 19 mils ±1 mil 1750µm x 1420µm x 483µm ±25.4µm

### INTERFACE MATERIALS:

### Glassivation:

Type: Nitride (S13N4) over Silox (SiO2, 5% Phos.) Silox Thickness:  $12k\dot{A} \pm 2k\dot{A}$  Nitride Thickness:  $3.5k\dot{A} \pm 1.5k\dot{A}$ 

### **Top Metallization:**

Type: Al, 1% Cu Thickness: 18kÅ ±2kÅ

### Substrate:

Linear Bipolar, DI

### **Backside Finish:**

Silicon

## Metallization Mask Layout

#### **ASSEMBLY RELATED INFORMATION:**

Substrate Potential (Powered Up): Unbiased

## ADDITIONAL INFORMATION:

Worst Case Current Density:  $<2 \times 10^5 \text{ A/cm}^2$ 

## Transistor Count:

HS-2620RH: 140 HS-2622RH: 140



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